NI 6132/6133 Specifications

This document lists the I/O terminal summary and specifications for the NI PXI-6132/6133.

For the most current edition of this document, refer to `ni.com/manuals`. Refer to the *DAQ Quick Start Guide* for more information about accessing documents on the NI-DAQ CD.

Note With NI-DAQmx, National Instruments has revised its terminal names so they are easier to understand and more consistent among NI hardware and software products. The revised terminal names used in this document are usually similar to the names they replace. For a complete list of Traditional NI-DAQ terminal names and their NI-DAQmx equivalents, refer to the *Terminal Name Equivalents* table in the *S Series Help*.

Table 1. I/O Terminal Summary

Terminal Name	Terminal Type and Direction	Impedance Input/ Output	Protection (Volts) On/Off	Source (mA at V)	Sink (mA at V)	Rise Time (ns)	Bias
AI <0..7>	AI	100 MΩ in parallel with 10 pF	35/25	—	—	—	±16 nA ±35 nA
AI GND	—	—	—	—	—	—	—
D GND	—	—	—	—	—	—	—
+5 V	—	0.1 Ω 0.45 Ω	Short-circuit to ground	1 A	—	—	—
P0.<0..7>	DIO	—	V_{CC} + 0.5	13 at (V_{CC} – 0.4)	24 at 0.4	1.1	50 kΩ pu
EXTSTROBE*	DO	—	—	3.5 at (V_{CC} – 0.4)	5 at 0.4	1.5	50 kΩ pu
PFI 0/ AI START TRIG	DIO	—	V_{CC} + 0.5	3.5 at (V_{CC} – 0.4)	5 at 0.4	1.5	50 kΩ pu
PFI 1/ AI REF TRIG	DIO	—	V_{CC} + 0.5	3.5 at (V_{CC} – 0.4)	5 at 0.4	1.5	50 kΩ pu
PFI 2	DIO	—	V_{CC} + 0.5	3.5 at (V_{CC} – 0.4)	5 at 0.4	1.5	50 kΩ pu

Table 1. I/O Terminal Summary (Continued)

Terminal Name	Terminal Type and Direction	Impedance Input/ Output	Protection (Volts) On/Off	Source (mA at V)	Sink (mA at V)	Rise Time (ns)	Bias
PFI 3/ CTR 1 SOURCE	DIO	—	V_{CC} + 0.5	3.5 at (V_{CC} – 0.4)	5 at 0.4	1.5	50 kΩ pu
PFI 4/ CTR 1 GATE	DIO	—	V_{CC} + 0.5	3.5 at (V_{CC} – 0.4)	5 at 0.4	1.5	50 kΩ pu
CTR 1 OUT	DO	—	—	3.5 at (V_{CC} – 0.4)	5 at 0.4	1.5	50 kΩ pu
PFI 5	DIO	—	V_{CC} + 0.5	3.5 at (V_{CC} – 0.4)	5 at 0.4	1.5	50 kΩ pu
PFI 6	DIO	—	V_{CC} + 0.5	3.5 at (V_{CC} – 0.4)	5 at 0.4	1.5	50 kΩ pu
PFI 7/ AI SAMP CLK	DIO	—	V_{CC} + 0.5	3.5 at (V_{CC} – 0.4)	5 at 0.4	1.5	50 kΩ pu
PFI 8/ CTR 0 SOURCE	DIO	—	V_{CC} + 0.5	3.5 at (V_{CC} – 0.4)	5 at 0.4	1.5	50 kΩ pu
PFI 9/ CTR 0 GATE	DIO	—	V_{CC} + 0.5	3.5 at (V_{CC} – 0.4)	5 at 0.4	1.5	50 kΩ pu
CTR 0 OUT	DO	—	—	3.5 at (V_{CC} – 0.4)	5 at 0.4	1.5	50 kΩ pu
FREQ OUT	DO	—	—	3.5 at (V_{CC} – 0.4)	5 at 0.4	1.5	50 kΩ pu

AI = Analog Input DIO = Digital Input/Output DO = Digital Output pu = pull-up

Note: The tolerance on the 50 kΩ pull-up resistors is large. Actual value might range between 17 kΩ and 100 kΩ.

Specifications

The following specifications are typical at 25 °C unless otherwise noted.

Analog Input

Input Characteristics

Number of channels

NI 6132.....4

NI 6133.....8

Type of ADC

Resolution.....14 bits, 1 in 16,384

Pipeline.....0

Sampling rate

Maximum ..... 2.5 MS/s per channel

Minimum ..... No minimum

Input impedance

AI – to AI GND ..... 100 MΩ in parallel with 10 pF

AI + to AI GND ..... 100 MΩ in parallel with 10 pF

Input bias current ..... ±2 pA typ, ±25 pA max

Input offset current ..... ±1 pA typ, ±10 pA max

Input coupling ..... DC

Max working voltage for all analog input channels

Positive input (AI +) ..... ±11 V for all ranges, Measurement Category I

Negative input (AI –) ..... ±11 V for all ranges, Measurement Category I

Caution Do *not* use for measurements within Categories II, III, and IV.

Overvoltage protection (AI +, AI –) ..... ±36 V

Input current during overvoltage conditions ..... ±20 mA max

Input FIFO size

NI 6132 ..... 16 MS

NI 6133 ..... 16 or 32 MS

Data transfers ..... DMA, interrupts, programmed I/O

DMA mode ..... Scatter-gather

DC Transfer Characteristics

INL ..... ±0.6 LSB typ, ±1 LSB max

DNL ..... ±0.25 typ, ±0.75 max, no missing codes

Absolute Accuracy

Nominal Range at Full Scale (V)	Residual Gain Error (ppm of Reading)	Gain Tempco (ppm/°C)	Reference Tempco	Residual Offset Error (ppm of Range)	Offset Tempco (ppm of Range/°C)	INL Error (ppm of Range)	Random Noise, σ (μVrms)	Absolute Accuracy at Full Scale[1] (μV)	Sensitivity[2] (μV)
±10	151	25	5	47	39	122	1080	4660	432.0
±5	176	25	5	40	43	122	546	2440	218.4
±2.5	207	25	5	47	61	122	305	1370	122.0
±1.25	234	25	5	45	78	122	172	740	68.8

AbsoluteAccuracy = Reading · (GainError) + Range · (OffsetError) + NoiseUncertainty

GainError = ResidualAIGainError + GainTempco · (TempChangeFromLastInternalCal) + ReferenceTempco · (TempChangeFromLastExternalCal)

OffsetError = ResidualAIOffsetError + OffsetTempco · (TempChangeFromLastInternalCal) + INL_Error

$$\text{NoiseUncertainty} = \frac{\text{RandomNoise} \cdot 3}{\sqrt{100}}$$ For a coverage factor of 3 σ and averaging 100 points.

[1] Absolute accuracy at full scale on the analog input channels is determined using the following assumptions:

TempChangeFromLastExternalCal = 10 °C

TempChangeFromLastInternalCal = 1 °C

number_of_readings = 100

CoverageFactor = 3 σ

For example, on the 10 V range, the absolute accuracy at full scale is as follows:

GainError = 151 ppm + 25 ppm · 1 + 5 ppm · 10 GainError = 226 ppm

OffsetError = 47 ppm + 39 ppm · 1 + 122 ppm OffsetError = 208 ppm

$$\text{NoiseUncertainty} = \frac{1{,}080\ \mu\text{V} \cdot 3}{\sqrt{100}}$$ NoiseUncertainty = 320 μV

AbsoluteAccuracy = 10 V · (GainError) + 10 V · (OffsetError) + NoiseUncertainty AbsoluteAccuracy = 4,660 μV

[2] Sensitivity is the smallest voltage change that can be detected. It is a function of noise.

Dynamic Characteristics

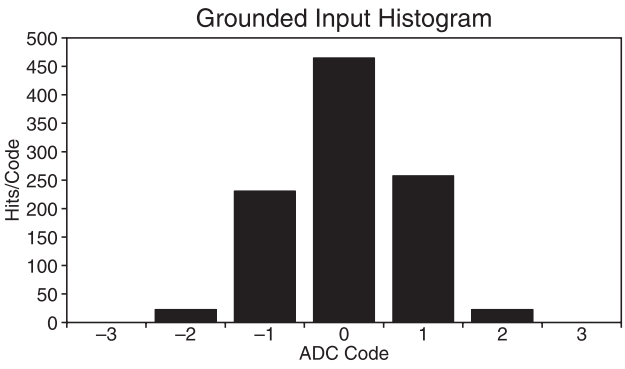
Phase mismatch..... ±2° at 1 MHz

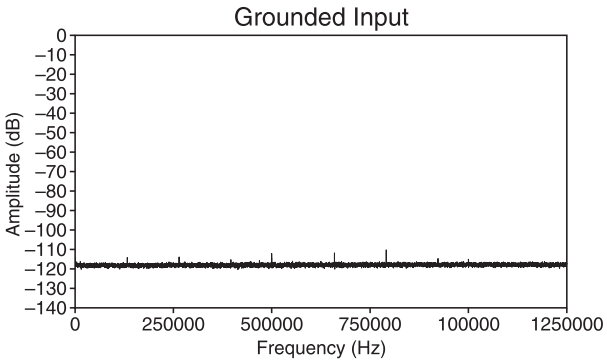
Table 2. NI 6132/6133 Analog Input Dynamic Characteristics

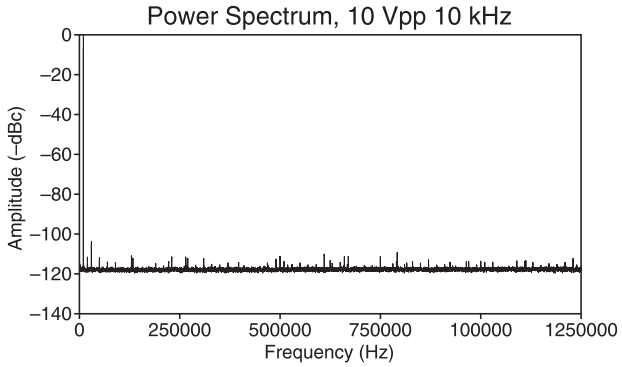
Input Range	Bandwidth[1] (MHz)	SFDR Typ[2] (dB)	CMRR[3] (dB)	System Noise[4] (LSB_{rms})	Crosstalk[5] (dB)	THD (dB at 10 kHz)
±10 V	1.3	95	70	0.78	–74	–101.1
±5 V	1.3	95	70	0.79	–74	–102.5
±2.5 V	1.25	96	70	0.86	–74	–102.2
±1.25 V	1.25	94	70	0.95	–74	–102.1

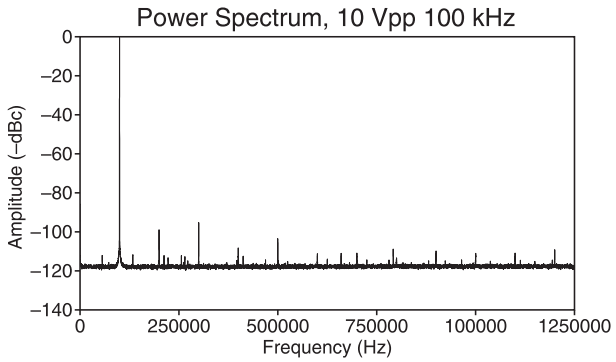
[1] –3 dB frequency for input amplitude at 10% of the input range (–20 dB)
[2] Measured at 100 kHz with twelfth-order bandpass filter after signal source
[3] DC to 60 Hz
[4] LSB_{rms}, including quantization
[5] DC to 100 kHz

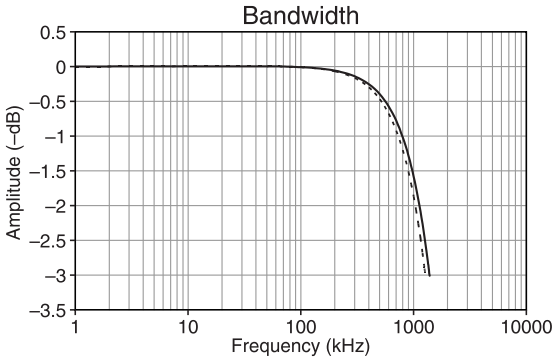
Typical Performance Graphs

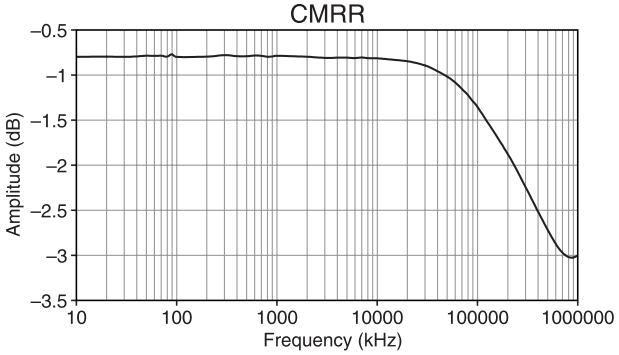


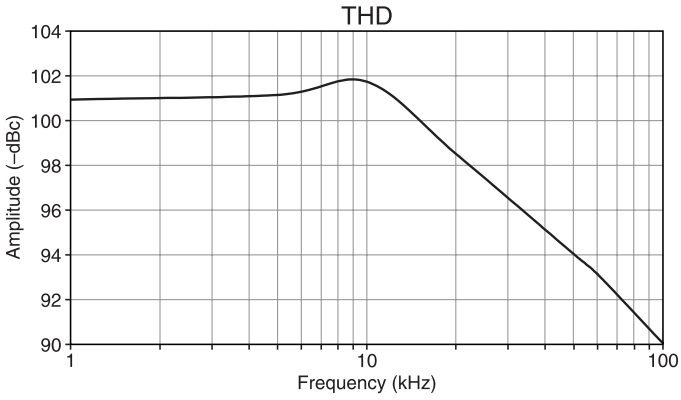












Stability

Recommended warm-up time ..... 15 min

Calibration

Level..... 5.000 V (±2.5 mV)
(actual value stored in EEPROM)

Temperature coefficient ..... ±5.0 ppm/°C max

Long-term stability..... ±15 ppm/$\sqrt{1{,}000\ \text{h}}$

Digital I/O

Number of channels ..... 8 input/output

Compatibility ..... TTL/CMOS

Table 3. Digital Logic Levels

Level	Min	Max
Input low voltage	0.0 V	0.8 V
Input high voltage	2.0 V	5.0 V
Input low current (V_{in} = 0 V)	—	–320 µA
Input high current (V_{in} = 5 V)	—	10 µA
Output low voltage (I_{OL} = 24 mA)	—	0.4 V
Output high voltage (I_{OH} = 13 mA)	4.35 V	—

Power-on state..... Input (high-impedance)

Data transfers ..... DMA, interrupts,
programmed I/O

Input buffer ..... 2,044 bytes

Output buffer..... 2,044 bytes

Transfer rate (1 word = 8 bits) ..... 10 Mwords/s

Timing I/O

Number of channels ..... 2 up/down counter/timers,
1 frequency scaler

Resolution

Counter/timers ..... 24 bits

Frequency scaler ..... 4 bits

Compatibility ..... TTL/CMOS

Base clocks available

Counter/timers ..... 20 MHz, 100 kHz

Frequency scaler ..... 10 MHz, 100 kHz

Base clock accuracy ..... ±0.01%

Max source frequency ..... 20 MHz

Min source pulse duration ..... 10 ns, edge-detect mode

Min gate pulse duration ..... 10 ns, edge-detect mode

Data transfers ..... DMA, interrupts, programmed I/O

DMA modes ..... Scatter-gather

Triggers

Analog Trigger

Source ..... All analog input channels

Level ..... ± full-scale

Slope ..... Positive or negative (software-selectable)

Resolution ..... 8 bits, 1 in 256

Hysteresis ..... Programmable

Bandwidth (–3 dB) ..... 5 MHz internal/external

Digital Trigger

Compatibility ..... TTL

Response ..... Rising or falling edge

Pulse width ..... 10 ns min

RTSI Trigger Lines (PCI Only)

Trigger lines <0..6>..... 7

RTSI clock 1

PXI Trigger Bus (PXI Only)

Trigger lines <0..6>..... 7

Star trigger..... 1

Bus Interface

Type ..... Master, slave

Power Requirement

+5 VDC (±5%)

NI 6132 ..... 2.2 A

NI 6133 ..... 3.0 A

+3.3 V

NI 6132 ..... 1.0 A

NI 6133 ..... 1.2 A

–12 VDC

NI 6132 ..... 45 mA

NI 6133 ..... 70 mA

Power available at I/O connector ..... +4.65 to +5.25 VDC at 1 A

Physical

Dimensions (not including connectors)

NI PCI-6132/6133..... 31.2 cm × 10.6 cm (12.3 × 4.2 in.)

NI PXI-6132/6133 ..... 16.0 cm × 10.0 cm (6.3 in. × 3.9 in.)

I/O connector..... 68-pin male SCSI-II type

Environmental

Operating temperature..... 0 to 50 °C

Storage temperature ..... –20 to 70 °C

Humidity .....10 to 90% RH, noncondensing

Maximum altitude.....2,000 m

Pollution Degree (indoor use only) 2

Safety

The NI 6132/6133 devices are designed to meet the requirements of the following standards of safety for electrical equipment for measurement, control, and laboratory use:

- IEC 61010-1, EN 61010-1
- UL 61010-1
- CAN/CSA-C22.2 No. 61010-1

Note For UL and other safety certifications, refer to the product label, or visit `ni.com/certification`, search by model number or product line, and click the appropriate link in the Certification column.

Electromagnetic Compatibility

Emissions.....EN 55011 Class A at 10 m
FCC Part 15A above 1 GHz

Immunity .....EN 61326:1997 + A2:2001, Table 1

EMC/EMI .....CE, C-Tick, and FCC Part 15 (Class A) Compliant

Note For EMC compliance, operate this device with shielded cabling.

CE Compliance

This product meets the essential requirements of applicable European Directives, as amended for CE marking, as follows:

Low-Voltage Directive (safety).....73/23/EEC

Electromagnetic Compatibility
Directive (EMC).....89/336/EEC

Note Refer to the Declaration of Conformity (DoC) for this product for any additional regulatory compliance information. To obtain the DoC for this product, visit `ni.com/certification`, search by model number or product line, and click the appropriate link in the Certification column.

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